NSN 5961-01-159-3170

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-159-3170 **Inclosure Material:** Glass **Overall Length:** Between 0.160 inches and 0.205 inches **Terminal Length:** 1.100 inches **Overall Diameter:** Between 0.080 inches and 0.107 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-41 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 1.00 amperes forward current, average absolute **Special Features:** Insulated tubing; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No